19.05mmx3.81mm LED LIGHT BAR

Part Number: KB-B100SURKW Hyper Red

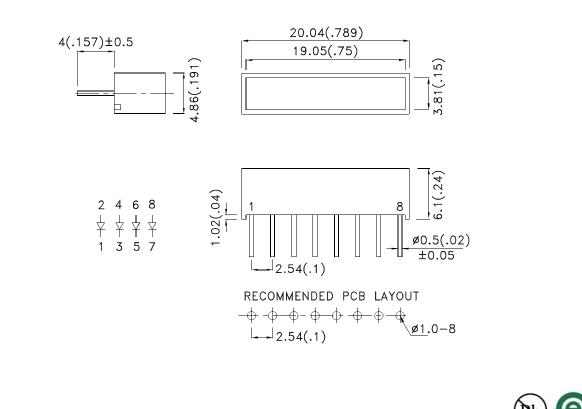
Features

- Uniform light emitting area.
- Low current operation.
- Easily mounted on P.C. boards.
- Flush mountable.
- Excellent on/off contrast.
- Can be used with panels and legend mounts.
- RoHS compliant.

Description

The Hyper Red source color devices are made with Al-GalnP on GaAs substrate Light Emitting Diode.

Package Dimensions& Internal Circuit Diagram



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Notes:

1. All dimensions are in millimeters (inches), Tolerance is ±0.25(0.01")unless otherwise noted.

2. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

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Selection Guide								
Part No.	Dice	Lens Type		cd) [1] 20mA				
			Min.	Тур.				
KB-B100SURKW	Hyper Red (AlGaInP)	WHITE DIFFUSED	70	305				

Note: 1. Luminous intensity/ luminous Flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Hyper Red	650		nm	I⊧=20mA
λD [1]	Dominant Wavelength	Hyper Red	630		nm	I⊧=20mA
Δλ1/2	Spectral Line Half-width	Hyper Red	28		nm	I⊧=20mA
С	Capacitance	Hyper Red	35		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	Hyper Red	1.95	2.5	V	IF=20mA
lr	Reverse Current	Hyper Red		10	uA	VR=5V

Notes:

1.Wavelength: +/-1nm. 2. Forward Voltage: +/-0.1V.

Absolute Maximum Ratings at TA=25°C

Parameter	Hyper Red	Units		
Power dissipation	75	mW		
DC Forward Current	30	mA		
Peak Forward Current [1]	185	mA		
Reverse Voltage	5	V		
Operating / Storage Temperature	-40°C To +85°C			
Lead Solder Temperature[2]	260°C For 3-5 Seconds			

Notes: 1. 1/10 Duty Cycle, 0.1ms Pulse Width. 2. 2mm below package base.

